

# NPN SILICON GERMANIUM RF TRANSISTOR NESG3031M05

## NPN SIGE RF TRANSISTOR FOR LOW NOISE, HIGH-GAIN AMPLIFICATION FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M05, 2012 PKG)

#### FEATURES

- The device is an ideal choice for low noise, high-gain amplification
- $$\begin{split} NF &= 0.6 \text{ dB TYP.}, \ G_a &= 16.0 \text{ dB TYP.} @ \text{ V}_{CE} &= 2 \text{ V}, \ Ic &= 6 \text{ mA}, \ f &= 2.4 \text{ GHz} \\ NF &= 0.95 \text{ dB TYP.}, \ G_a &= 10.0 \text{ dB TYP.} @ \text{ V}_{CE} &= 2 \text{ V}, \ Ic &= 6 \text{ mA}, \ f &= 5.2 \text{ GHz} \\ NF &= 1.1 \text{ dB TYP.}, \ G_a &= 9.5 \text{ dB TYP.} @ \text{ V}_{CE} &= 2 \text{ V}, \ Ic &= 6 \text{ mA}, \ f &= 5.8 \text{ GHz} \end{split}$$
- Maximum stable power gain: MSG = 14.0 dB TYP. @ Vce = 3 V, Ic = 20 mA, f = 5.8 GHz
- SiGe HBT technology (UHS3) adopted: fmax = 110 GHz
- Flat-lead 4-pin thin-type super minimold (M05, 2012 PKG)

#### ★ ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
NESG3031M05	NESG3031M05-A	Flat-lead 4-pin thin-type super minimold (M05, 2012 PKG)	50 pcs (Non reel)	<ul><li>8 mm wide embossed taping</li><li>Pin 3 (Collector), Pin 4 (Emitter) face the</li></ul>
NESG3031M05-T1	NESG3031M05-T1-A	(Pb-Free)	3 kpcs/reel	perforation side of the tape

**Remark** To order evaluation samples, contact your nearby sales office. Unit sample quantity is 50 pcs.

#### ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	12.0	V
Collector to Emitter Voltage	Vceo	4.3	V
Emitter to Base Voltage	Vebo	1.5	V
Collector Current	lc	35	mA
Total Power Dissipation	Ptot Note	150	mW
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-65 to +150	°C

**Note** Mounted on 1.08  $\text{cm}^2 \times 1.0 \text{ mm}$  (t) glass epoxy PWB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

## ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
	Symbol	Test Conditions	IVIIIN.	ITF.	WAA.	Unit
DC Characteristics			ı — — —			
Collector Cut-off Current	Ісво	$V_{CB} = 5 V$ , $I_E = 0 mA$	-	_	100	nA
Emitter Cut-off Current	Іево	$V_{EB} = 1 V$ , $I_C = 0 mA$	-	-	100	nA
DC Current Gain	hfe <sup>Note 1</sup>	Vce = 2 V, Ic = 6 mA	220	300	380	-
RF Characteristics	RF Characteristics					
Insertion Power Gain	S <sub>21e</sub>   <sup>2</sup>	Vce = 3 V, Ic = 20 mA, f = 5.8 GHz	6.0	8.5	-	dB
Noise Figure (1)	NF	$\label{eq:Vce} \begin{array}{l} V_{CE} = 2 \ V, \ I_C = 6 \ mA, \ f = 2.4 \ GHz, \\ Z_S = Z_{Sopt}, \ Z_L = Z_{Lopt} \end{array}$	-	0.6	-	dB
Noise Figure (2)	NF	$\label{eq:Vce} \begin{array}{l} V_{CE} = 2 \ V, \ I_C = 6 \ mA, \ f = 5.2 \ GHz, \\ Z_S = Z_{Sopt}, \ Z_L = Z_{Lopt} \end{array}$	-	0.95	-	dB
Noise Figure (3)	NF	$\label{eq:Vce} \begin{array}{l} V_{CE} = 2 \ V, \ I_C = 6 \ mA, \ f = 5.8 \ GHz, \\ Z_S = Z_{Sopt}, \ Z_L = Z_{Lopt} \end{array}$	-	1.1	1.5	dB
Associated Gain (1)	Ga	$\label{eq:Vce} \begin{array}{l} V_{CE} = 2 \ V, \ I_C = 6 \ mA, \ f = 2.4 \ GHz, \\ Z_S = Z_{Sopt}, \ Z_L = Z_{Lopt} \end{array}$	-	16.0	-	dB
Associated Gain (2)	Ga	$\label{eq:Vce} \begin{array}{l} V_{CE} = 2 \ V, \ I_C = 6 \ mA, \ f = 5.2 \ GHz, \\ Z_S = Z_{Sopt}, \ Z_L = Z_{Lopt} \end{array}$	-	10.0	-	dB
Associated Gain (3)	Ga	$\label{eq:Vce} \begin{array}{l} V_{CE} = 2 \ V, \ I_C = 6 \ mA, \ f = 5.8 \ GHz, \\ Z_S = Z_{Sopt}, \ Z_L = Z_{Lopt} \end{array}$	7.5	9.5	-	dB
Reverse Transfer Capacitance	Cre Note 2	Vсв = 2 V, I <sub>E</sub> = 0 mA, f = 1 MHz	-	0.15	0.25	pF
Maximum Stable Power Gain	MSG <sup>Note</sup> 3	Vce = 3 V, Ic = 20 mA, f = 5.8 GHz	11.0	14.0	-	dB
Gain 1 dB Compression Output Power	Po (1 dB)	$\label{eq:Vce} \begin{array}{l} V_{CE}=3~V,~Ic~(\mbox{\tiny set})=20~mA,\\ f=5.8~GHz,~Zs=Z_{Sopt},~ZL=Z_{Lopt} \end{array}$	-	13.0	_	dBm
3rd Order Intermodulation Distortion Output Intercept Point	OIP <sub>3</sub>	$\label{eq:Vce} \begin{array}{l} V_{CE} = 3 \ V, \ I_{C \ (set)} = 20 \ mA, \\ f = 5.8 \ GHz, \ Z_{S} = Z_{Sopt}, \ Z_{L} = Z_{Lopt} \end{array}$	-	18.0	-	dBm

Notes 1. Pulse measurement: PW  $\leq$  350  $\mu s,$  Duty Cycle  $\leq$  2%

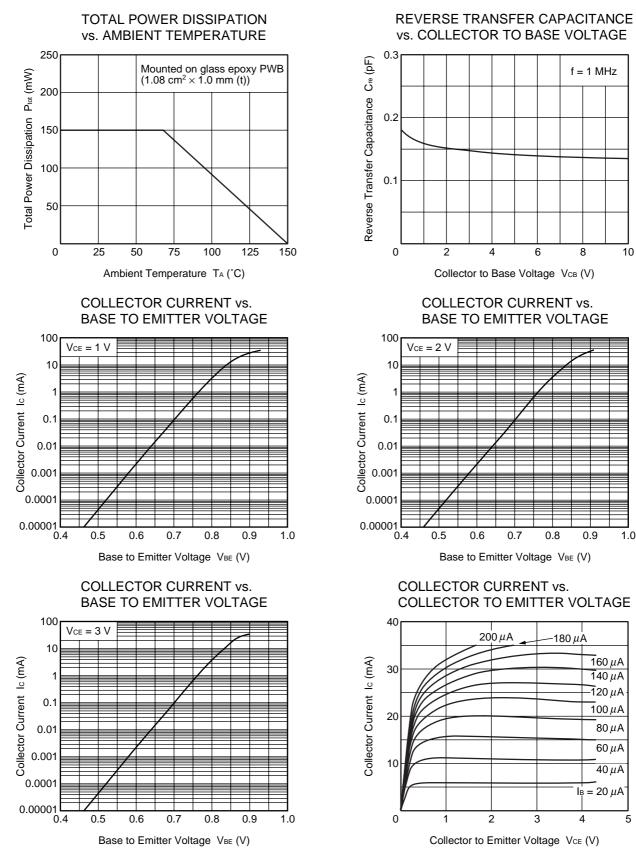
2. Collector to base capacitance when the emitter grounded

**3.** MSG = 
$$\frac{S_{21}}{S_{12}}$$

### **hfe CLASSIFICATION**

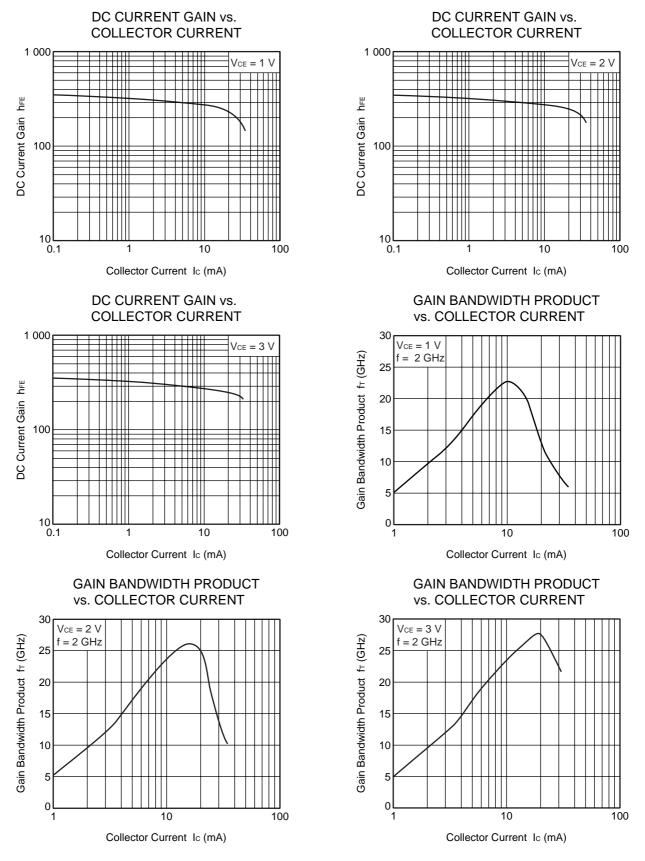
Rank	FB	
Marking	T1K	
hfe Value	220 to 380	

\*

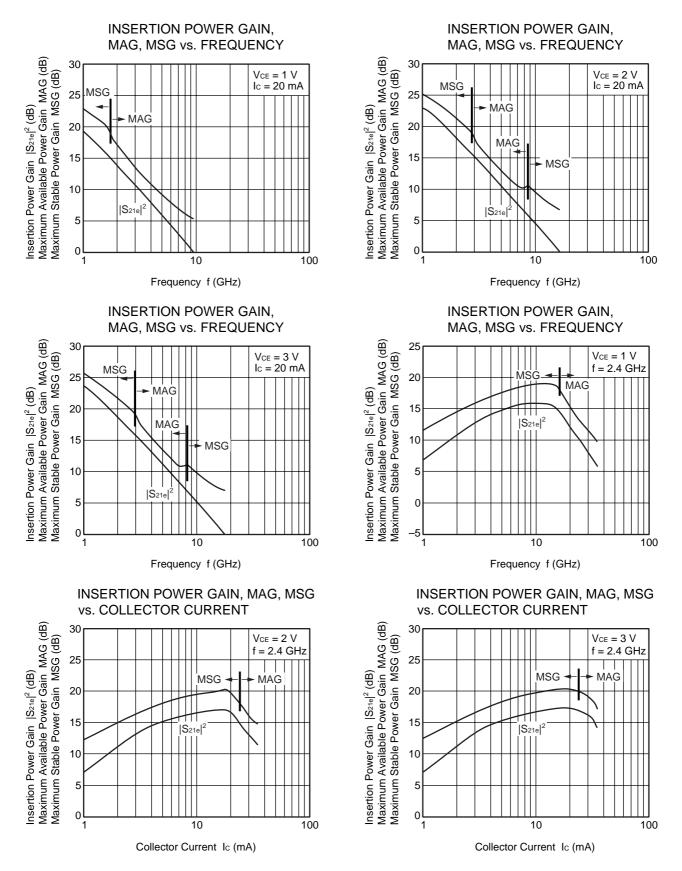


#### TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

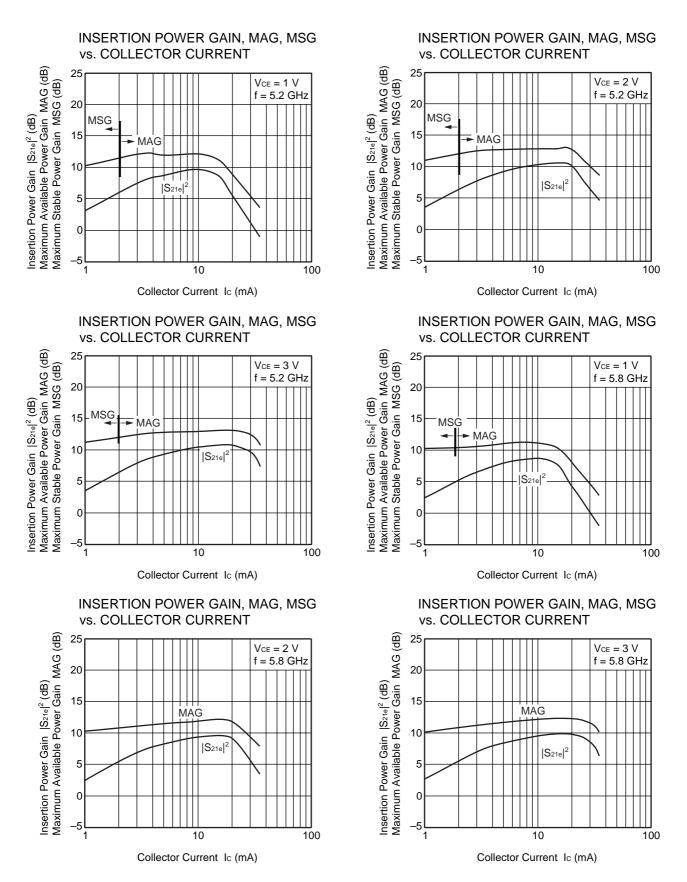
**Remark** The graphs indicate nominal characteristics.



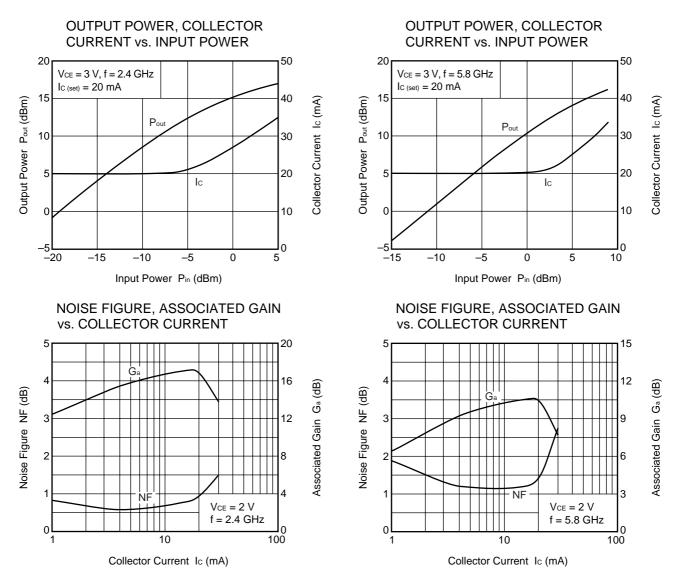
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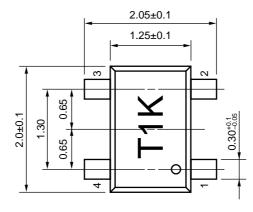
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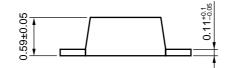


Remark The graphs indicate nominal characteristics.

### PACKAGE DIMENSIONS

## FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M05, 2012 PKG) (UNIT: mm)





#### **PIN CONNECTIONS**

- 1. Base
- 2. Emitter
- 3. Collector
- 4. Emitter

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#### ▶ For further information, please contact

NEC Compound Semiconductor Devices, Ltd. http://www.ncsd.necel.com/ E-mail: salesinfo@ml.ncsd.necel.com (sales and general) techinfo@ml.ncsd.necel.com (technical) Sales Division TEL: +81-44-435-1573 FAX: +81-44-435-1579

**NEC Compound Semiconductor Devices Hong Kong Limited** 

E-mail: ncsd-hk@elhk.nec.com.hk (sales, technical and general)

Hong Kong Head Office	TEL: +852-3107-7303	FAX: +852-3107-7309
Taipei Branch Office	TEL: +886-2-8712-0478	FAX: +886-2-2545-3859
Korea Branch Office	TEL: +82-2-558-2120	FAX: +82-2-558-5209

NEC Electronics (Europe) GmbH http://www.ee.nec.de/ TEL: +49-211-6503-0 FAX: +49-211-6503-1327

California Eastern Laboratories, Inc. http://www.cel.com/ TEL: +1-408-988-3500 FAX: +1-408-988-0279



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Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
РВВ	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

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